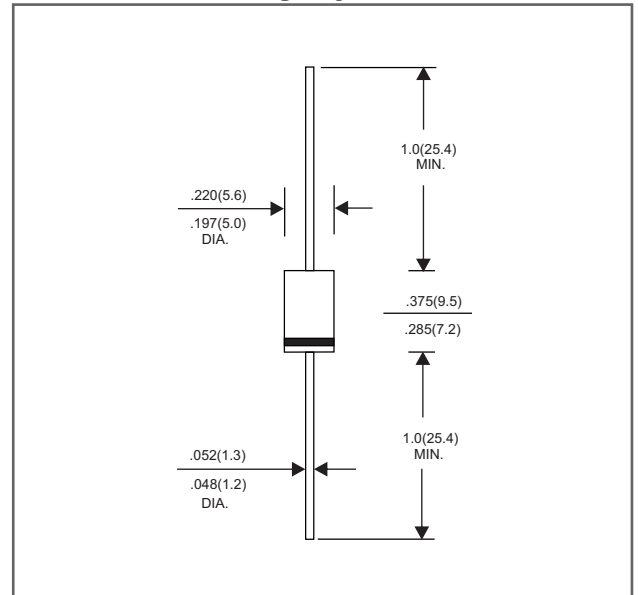




## 3.0A Leaded Type Schottky Barrier Rectifiers - 20V-200V

### Package outline

#### DO-201AD



Dimensions in inches and (millimeters)

### Features

- Axial lead type devices for through hole design.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability.
- Guardring for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228
- Suffix "-H" indicates Halogen free parts, ex. MBR320NG-H.

### Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, DO-201AD
- Terminals : Solder plated, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity :Color band denotes cathode end
- Mounting Position : Any
- Weight : Approximated 1.10 gram

### Maximum ratings (AT $T_A=25^{\circ}\text{C}$ unless otherwise noted)

| PARAMETER                  | CONDITIONS  | Symbol          | MIN. | TYP. | MAX. | UNIT                        |
|----------------------------|---|-----------------|------|------|------|-----------------------------|
| Forward rectified current  | See Fig.2   | $I_O$           |      |      | 3.0  | A                           |
| Forward surge current      | 8.3ms single half sine-wave superimposed on rate load (JEDEC methode) | $I_{FSM}$       |      |      | 80   | A                           |
| Reverse current            | $V_R = V_{RRM} \quad T_J = 25^{\circ}\text{C}$                        | $I_R$           |      |      | 0.5  | mA                          |
|                            | $V_R = V_{RRM} \quad T_J = 100^{\circ}\text{C}$                       |                 |      |      | 30   |                             |
| Thermal resistance         | Junction to ambient   | $R_{\theta JA}$ |      | 20   |      | $^{\circ}\text{C}/\text{W}$ |
| Diode junction capacitance | f=1MHz and applied 4V DC reverse voltage                              | $C_J$           |      | 250  |      | pF                          |
| Storage temperature        |   | $T_{STG}$       | -65  |      | +175 | $^{\circ}\text{C}$          |

| SYMBOLS   | $V_{RRM}^{*1}$<br>(V) | $V_{RMS}^{*2}$<br>(V) | $V_R^{*3}$<br>(V) | $V_F^{*4}$<br>(V) | Operating temperature<br>$T_J, (^{\circ}\text{C})$ |
|-----------|-----------------------|-----------------------|-------------------|-------------------|--|
| MBR320NG  | 20                    | 14                    | 20                | 0.55              | -55 to +125  |
| MBR330NG  | 30                    | 21                    | 30                |                   |  |
| MBR340NG  | 40                    | 28                    | 40                |                   |  |
| MBR350NG  | 50                    | 35                    | 50                | 0.70              | -55 to +150  |
| MBR360NG  | 60                    | 42                    | 60                |                   |  |
| MBR380NG  | 80                    | 56                    | 80                | 0.85              |  |
| MBR3100NG | 100                   | 70                    | 100               |                   |  |
| MBR3150NG | 150                   | 105                   | 150               | 0.90              |  |
| MBR3200NG | 200                   | 140                   | 200               | 0.95              |  |

\*1 Repetitive peak reverse voltage

\*2 RMS voltage

\*3 Continuous reverse voltage

\*4 Maximum forward voltage@ $I_F=3.0\text{A}$

## Rating and characteristic curves

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

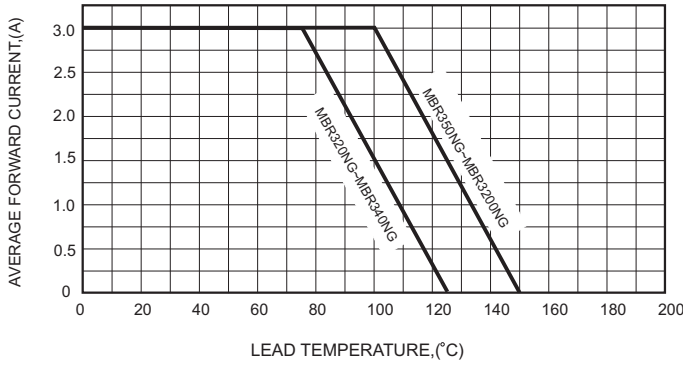


FIG.2-TYPICAL FORWARD CHARACTERISTICS

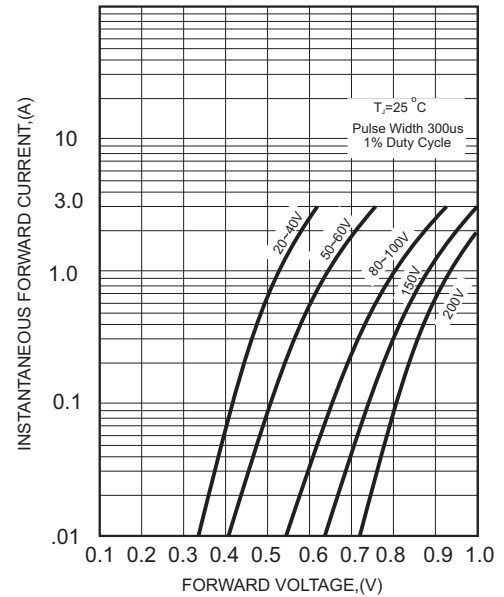


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

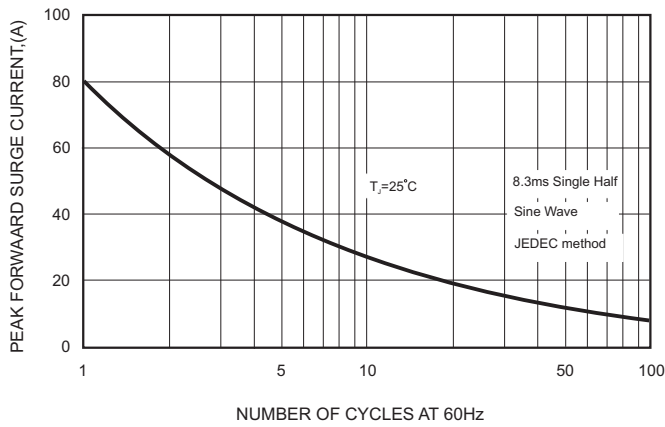


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

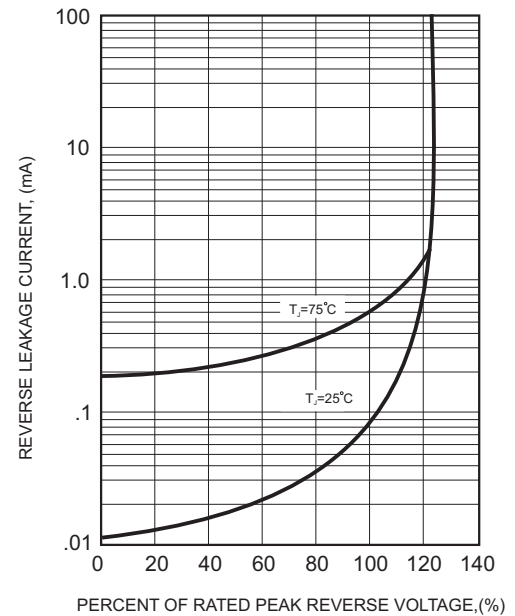


FIG.4-TYPICAL JUNCTION CAPACITANCE

